NSN 5962-00-137-5012

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-00-137-5012 **Body Length:** 0.390 inches **Body Width:** 0.390 inches **Body Height:** 0.070 inches **Maximum Power Dissipation Rating:** 307.2 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and monolithic and positive outputs and bipolar and negative outputs and unipolar and programmable and programmed and w/enable and wire-or outputs **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Flat pack **Output Logic Form:** P-type metal oxide-semiconductor logic **Input Circuit Pattern:** 12 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -20.0 volts power source and 8.3 volts power source **Time Rating Per Chacteristic:** 900.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Rom **Test Data Document:** 09128-d34005544 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 30 flat leads Shelf Life: N/a **Unit Of Measure:**

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Demilitarization: Yes - demil/mli